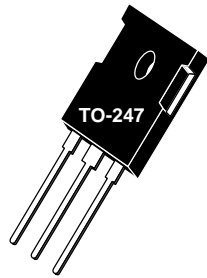
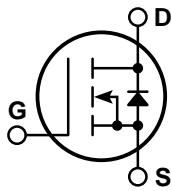




**THE DATASHEET OF
APT6040BN**





APT6040BN 600V 18.0A 0.40Ω

APT6045BN 600V 17.0A 0.45Ω

POWER MOS IV®

N-CHANNEL ENHANCEMENT MODE HIGH VOLTAGE POWER MOSFETS

MAXIMUM RATINGS

All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

| Symbol | Parameter | APT 6040BN | APT 6045BN | UNIT |
|----------------|---|------------|------------|-------|
| V_{DSS} | Drain-Source Voltage | 600 | 600 | Volts |
| I_D | Continuous Drain Current @ $T_C = 25^\circ\text{C}$ | 18 | 17 | Amps |
| I_{DM} | Pulsed Drain Current ① | 72 | 68 | |
| V_{GS} | Gate-Source Voltage | ± 30 | | Volts |
| P_D | Total Power Dissipation @ $T_C = 25^\circ\text{C}$ | 310 | | Watts |
| | Linear Derating Factor | 2.48 | | W/°C |
| T_J, T_{STG} | Operating and Storage Junction Temperature Range | -55 to 150 | | °C |
| T_L | Lead Temperature: 0.063" from Case for 10 Sec. | 300 | | |

STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Characteristic / Test Conditions / Part Number | MIN | TYP | MAX | UNIT |
|--------------|--|-----------|-----|-----------|---------------|
| BV_{DSS} | Drain-Source Breakdown Voltage ($V_{GS} = 0V, I_D = 250 \mu\text{A}$) | APT6040BN | 600 | | Volts |
| | | APT6045BN | 600 | | |
| $I_{D(ON)}$ | On State Drain Current ② ($V_{DS} > I_{D(ON)} \times R_{DS(ON)}$ Max, $V_{GS} = 10V$) | APT6040BN | 18 | | Amps |
| | | APT6045BN | 17 | | |
| $R_{DS(ON)}$ | Drain-Source On-State Resistance ② ($V_{GS} = 10V, 0.5 I_D$ [Cont.]) | APT6040BN | | 0.40 | Ohms |
| | | APT6045BN | | 0.45 | |
| I_{DSS} | Zero Gate Voltage Drain Current ($V_{DS} = V_{DSS}, V_{GS} = 0V$) | | | 250 | μA |
| | Zero Gate Voltage Drain Current ($V_{DS} = 0.8 V_{DSS}, V_{GS} = 0V, T_C = 125^\circ\text{C}$) | | | 1000 | |
| I_{GSS} | Gate-Source Leakage Current ($V_{GS} = \pm 30V, V_{DS} = 0V$) | | | ± 100 | nA |
| $V_{GS(TH)}$ | Gate Threshold Voltage ($V_{DS} = V_{GS}, I_D = 1.0\text{mA}$) | 2 | | 4 | Volts |

THERMAL CHARACTERISTICS

| Symbol | Characteristic | MIN | TYP | MAX | UNIT |
|-----------------|---------------------|-----|-----|------|------|
| $R_{\theta JC}$ | Junction to Case | | | 0.40 | °C/W |
| $R_{\theta JA}$ | Junction to Ambient | | | 40 | |

CAUTION: These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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DYNAMIC CHARACTERISTICS

APT6040/6045BN

| Symbol | Characteristic | Test Conditions | MIN | TYP | MAX | UNIT |
|-------------------|--------------------------------|--|-----|------|------|------|
| C_{iss} | Input Capacitance | $V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1\text{ MHz}$ | | 2400 | 2950 | pF |
| C_{oss} | Output Capacitance | | | 436 | 610 | |
| C_{rss} | Reverse Transfer Capacitance | | | 154 | 230 | |
| Q_g | Total Gate Charge ^③ | $V_{GS} = 10V$ $V_{DD} = 0.5 V_{DSS}$ $I_D = I_D [\text{Cont.}] @ 25^\circ\text{C}$ | | 87 | 130 | nC |
| Q_{gs} | Gate-Source Charge | | | 11 | 16 | |
| Q_{gd} | Gate-Drain ("Miller") Charge | | | 46 | 69 | |
| $t_d(\text{on})$ | Turn-on Delay Time | $V_{GS} = 15V$ $V_{DD} = 0.5 V_{DSS}$ $I_D = I_D [\text{Cont.}] @ 25^\circ\text{C}$ $R_G = 1.8\Omega$ | | 14 | 28 | ns |
| t_r | Rise Time | | | 23 | 46 | |
| $t_d(\text{off})$ | Turn-off Delay Time | | | 63 | 95 | |
| t_f | Fall Time | | | 23 | 46 | |

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS

| Symbol | Characteristic / Test Conditions / Part Number | MIN | TYP | MAX | UNIT |
|----------|---|-----------|-----|-----|---------|
| I_S | Continuous Source Current (Body Diode) | APT6040BN | | 18 | Amps |
| | | APT6045BN | | 17 | |
| I_{SM} | Pulsed Source Current ^① (Body Diode) | APT6040BN | | 72 | Amps |
| | | APT6045BN | | 68 | |
| V_{SD} | Diode Forward Voltage ^② ($V_{GS} = 0V, I_S = -I_D [\text{Cont.}]$) | | | 1.3 | Volts |
| t_{rr} | Reverse Recovery Time ($I_S = -I_D [\text{Cont.}], di_S/dt = 100A/\mu s$) | | 334 | 668 | ns |
| Q_{rr} | Reverse Recovery Charge ($I_S = -I_D [\text{Cont.}], di_S/dt = 100A/\mu s$) | | 5 | 10 | μC |

SAFE OPERATING AREA CHARACTERISTICS

| Symbol | Characteristic | Test Conditions / Part Number | MIN | TYP | MAX | UNIT |
|----------|---------------------------|---|-----|-----|-----|-------|
| SOA1 | Safe Operating Area | $V_{DS} = 0.4 V_{DSS}, I_{DS} = P_D / 0.4 V_{DSS}, t = 1\text{ Sec.}$ | 310 | | | Watts |
| SOA2 | Safe Operating Area | $I_{DS} = I_D [\text{Cont.}], V_{DS} = P_D / I_D [\text{Cont.}], t = 1\text{ Sec.}$ | 310 | | | |
| I_{LM} | Inductive Current Clamped | APT6040BN | 72 | | | Amps |
| | | APT6045BN | 68 | | | |

① Repetitive Rating: Pulse width limited by maximum junction temperature. See Transient Thermal Impedance Curve. (Fig.1)

② Pulse Test: Pulse width < 380 μs , Duty Cycle < 2%

③ See MIL-STD-750 Method 3471

APT Reserves the right to change, without notice, the specifications and information contained herein.

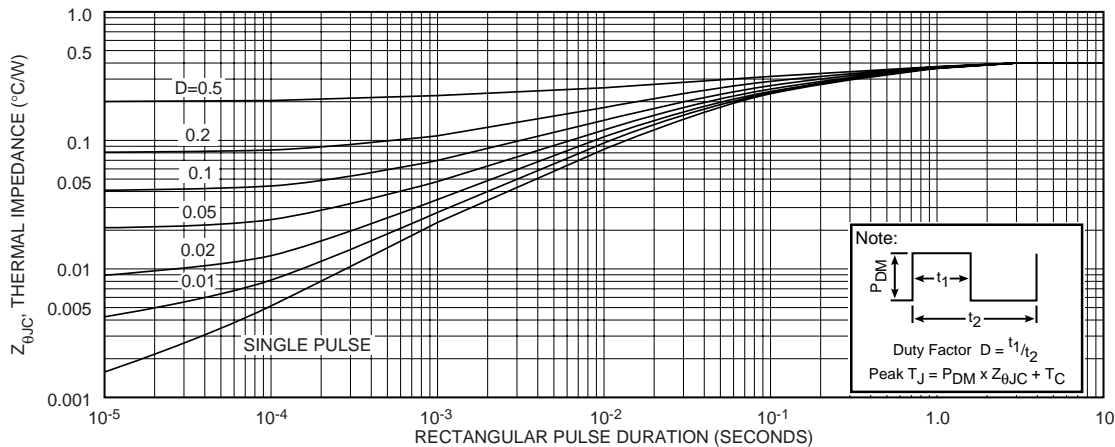


FIGURE 1, MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs PULSE DURATION

APT6040/6045BN

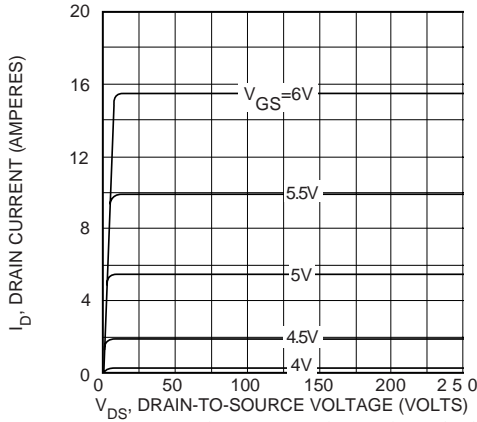


FIGURE 2, TYPICAL OUTPUT CHARACTERISTICS

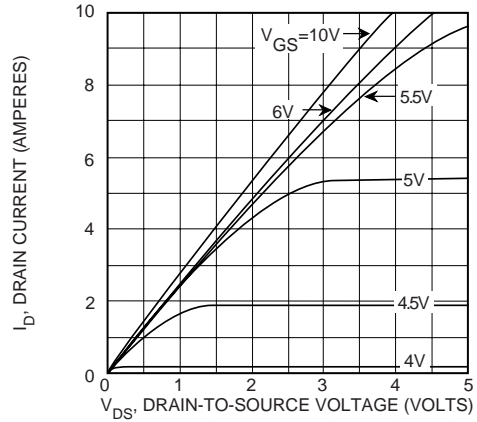


FIGURE 3, TYPICAL OUTPUT CHARACTERISTICS

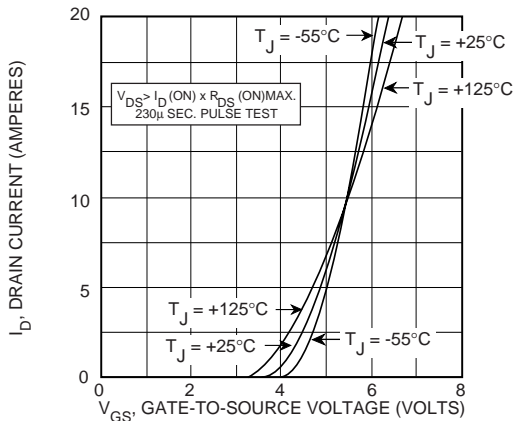


FIGURE 4, TYPICAL TRANSFER CHARACTERISTICS

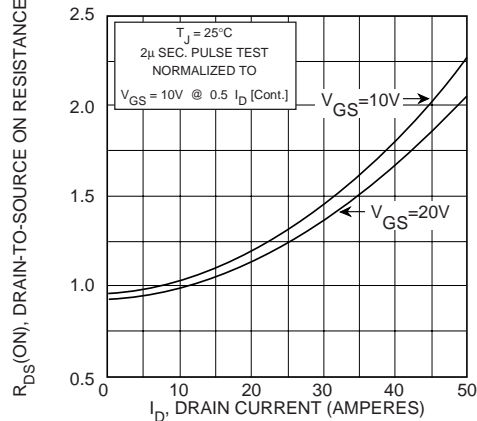


FIGURE 5, $R_{DS(ON)}$ vs DRAIN CURRENT

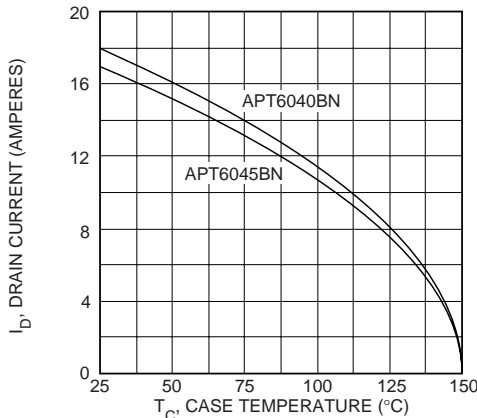


FIGURE 6, MAXIMUM DRAIN CURRENT vs CASE TEMPERATURE

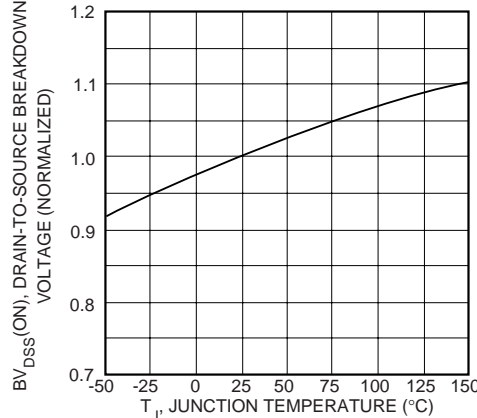


FIGURE 7, BREAKDOWN VOLTAGE vs TEMPERATURE

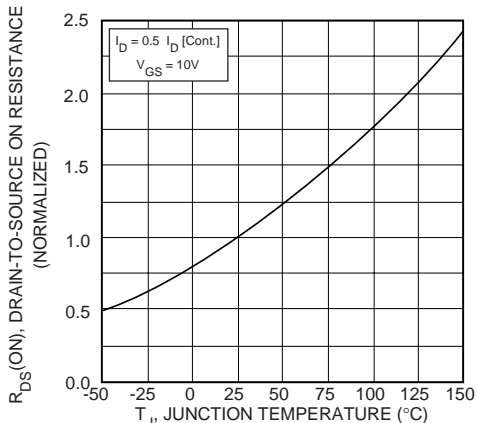


FIGURE 8, ON-RESISTANCE vs. TEMPERATURE

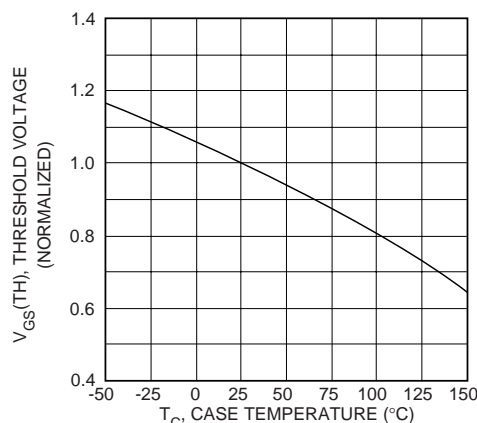


FIGURE 9, THRESHOLD VOLTAGE vs TEMPERATURE

APT6040/6045BN

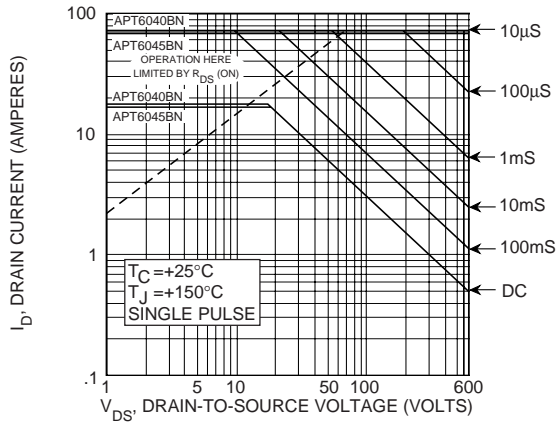


FIGURE 10, MAXIMUM SAFE OPERATING AREA

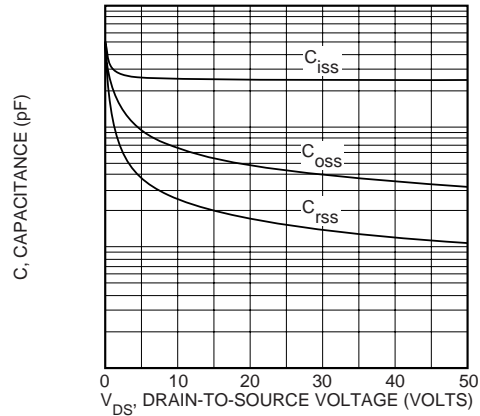


FIGURE 11, TYPICAL CAPACITANCE vs DRAIN-TO-SOURCE VOLTAGE

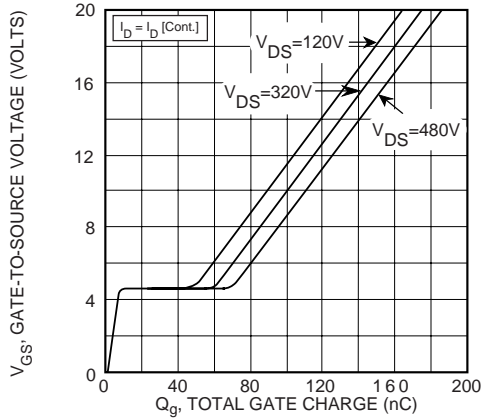


FIGURE 12, GATE CHARGES vs GATE-TO-SOURCE VOLTAGE

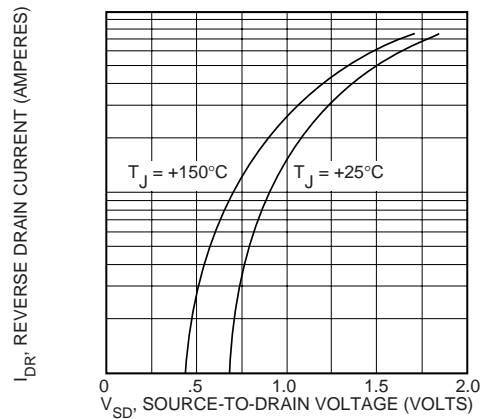
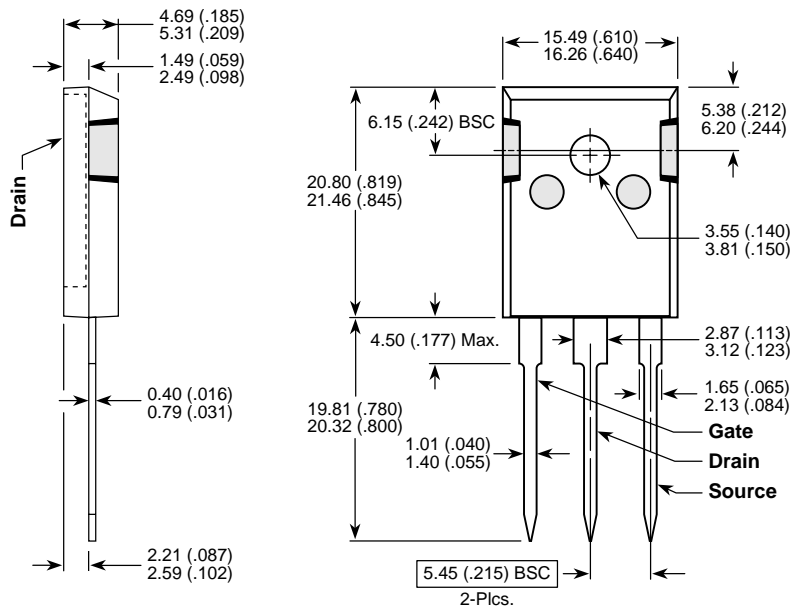


FIGURE 13, TYPICAL SOURCE-DRAIN DIODE FORWARD VOLTAGE

TO-247AD Package Outline



Dimensions in Millimeters and (Inches)

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- ⊖ [View APT6040BN on WIN SOURCE](#)
- ⊖ [Microsemi Corporation Information](#)

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